



LIGITEK

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INFRARED EMITTING DIODES

LHIR13743-T50

DATA SHEET

DOC. NO : QW0905-LHIR13743-T50

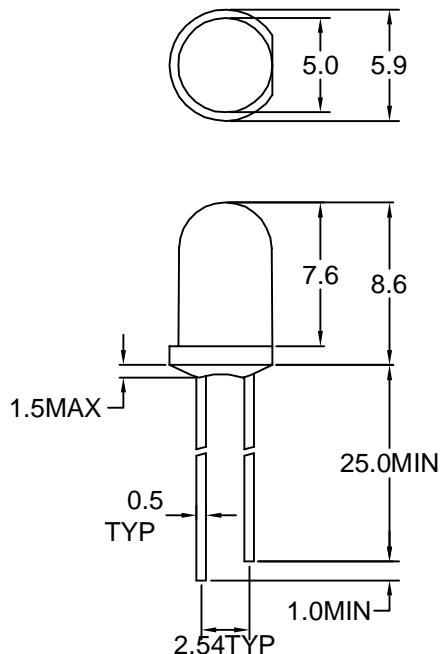
REV. : B

DATE : 30 - May - 2005

PART NO. LHIR13743-T50

Page 1/4

Package Dimensions



Note : 1. All dimension are in millimeter tolerance is $\pm 0.25\text{mm}$ unless otherwise noted.
 2. Specifications are subject to change without notice.

Features:

1. High radiant intensity.
2. Suitable for pulse applications.
3. Low average degradation.

Descriptions:

The LHIR13743-T50 series are super-high efficiency Gallium Aluminum Arsenide infrared emitting diodes encapsulated in water clear plastic T-1 3/4 package individually

Device Selection Guide:

PART NO	MATERIAL	LENS COLOR
LHIR13743-T50	AlGaAs	Water Clear



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PART NO. LHIR13743-T50

Page 2/4

Absolute Maximum Ratings at Ta=25

Parameter	Symbol	Ratings	UNIT
		HIR	
Forward Current	IF	50	mA
Peak Forward Current (300PPS,1 μ s Pulse)	IFP	3	A
Power Dissipation	PD	100	mW
Reverse Voltagev	Vr	5	V
Operating Temperature	T _{opr}	-55 ~ +100	
Storage Temperature	T _{stg}	-55 ~ +100	
Soldering Temperature	T _{sol}	Max 260 for 5 sec Max (2mm from body)	

Electrical Optical Characteristics (Aa=25)

PARAMETER	SYMBOL	Min.	Typ.	Max.	UNIT	TEST CONDITION
Radiant Intensity	I _e	6.0	12.5		mW/sr	IF=50mA
Aperture Radiant Incidence	E _e	1.0	1.8		mW/cm ²	IF=50mA
Peak Wavelength	peak		850		nm	IF=50mA
Spectral Line Half Width			50		nm	IF=50mA
Forward Voltage	V _F		1.5	2.0	V	IF=50mA
Reverse Current	I _R			100	μ A	VR=5V
Viewing Angle	2 1/2		60		deg	

Note : 1.The forward voltage data did not including ±0.1V testing tolerance.

2. The radiant intensity data did not including ±15% testing tolerance.



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PART NO. LHIR13743-T50

Page 3/4

Typical Electro-Optical Characteristics Curve

HIR CHIP

Fig.1 Forward Current vs. Rorward Voltage

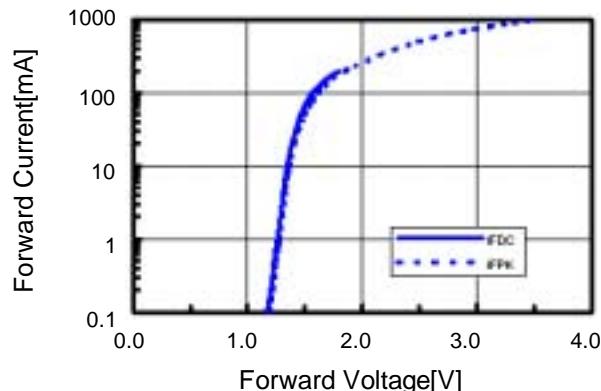


Fig.2 Relative Radiant Power vs. Wavelength

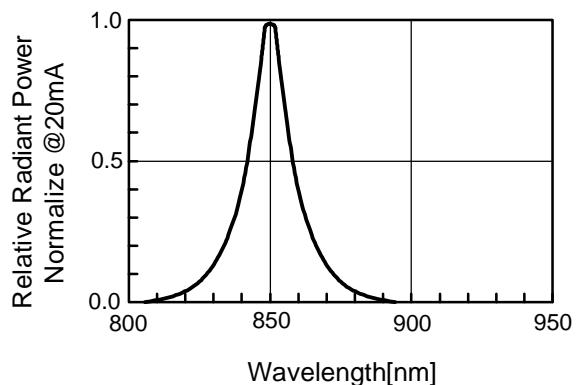


Fig.3 Relative Radiant Power
vs. Forward DC Current

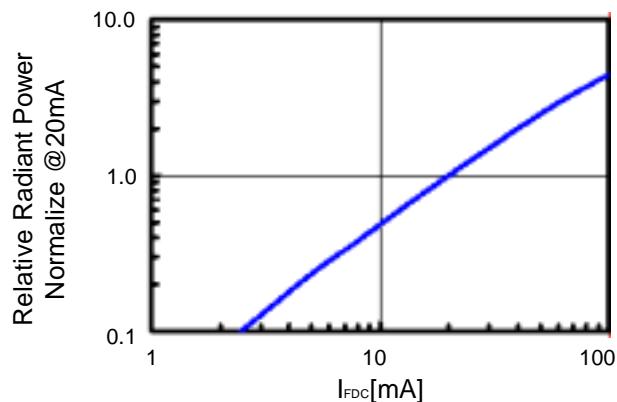


Fig.4 Relative Radiant Power
vs. Forward Peak Current

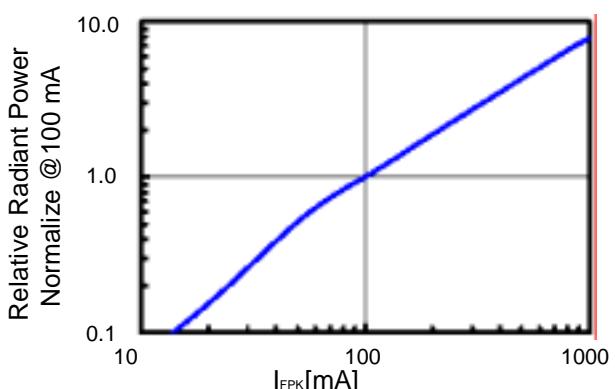


Fig.5 Forward DC Voltage vs. Temperature

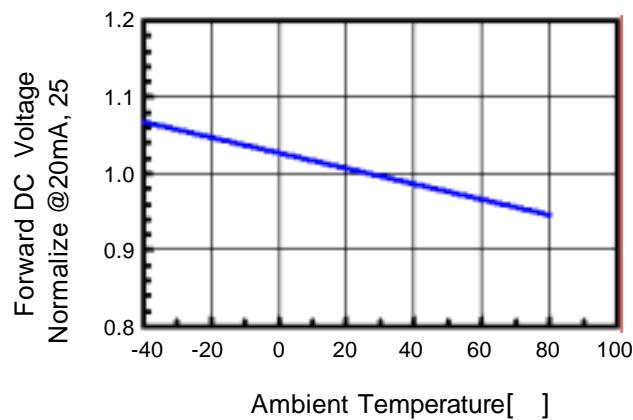
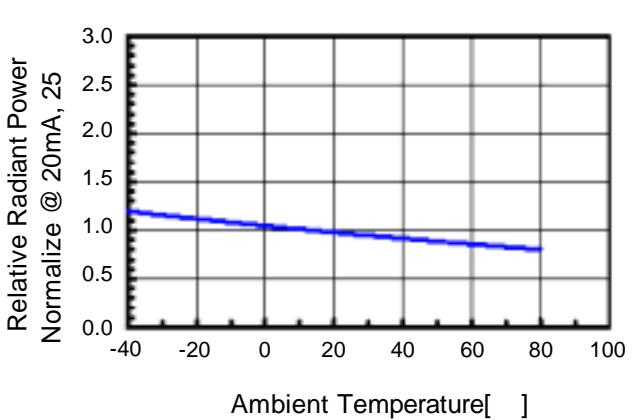


Fig.6 Relative Radiant Power vs. Temperature





PART NO. LHIR13743-T50

Page 4/4

Reliability Test:

Test Item	Test Condition	Description	Reference Standard
Operating Life Test	1.Under Room Temperature 2.If=20mA 3.t=1000 hrs (-24hrs, +72hrs)	This test is conducted for the purpose of determining the resistance of a part in electrical and thermal stressed.	MIL-STD-750: 1026 MIL-STD-883: 1005 JIS C 7021: B-1
High Temperature Storage Test	1.Ta=105 ±5 2.t=1000 hrs (-24hrs, +72hrs)	The purpose of this is the resistance of the device which is laid under condition of high temperature for hours.	MIL-STD-883:1008 JIS C 7021: B-10
Low Temperature Storage Test	1.Ta=-40 ±5 2.t=1000 hrs (-24hrs, +72hrs)	The purpose of this is the resistance of the device which is laid under condition of low temperature for hours.	JIS C 7021: B-12
High Temperature High Humidity Test	1.Ta=65 ±5 2.RH=90%~95% 3.t=240hrs ±2hrs	The purpose of this test is the resistance of the device under tropical for hours.	MIL-STD-202:103B JIS C 7021: B-11
Thermal Shock Test	1.Ta=105 ±5 &-40 ±5 (10min) (10min) 2.total 10 cycles	The purpose of this is the resistance of the device to sudden extreme changes in high and low temperature.	MIL-STD-202: 107D MIL-STD-750: 1051 MIL-STD-883: 1011
Solder Resistance Test	1.T.Sol=260 ±5 2.Dwell time= 10 ±1sec.	This test intended to determine the thermal characteristic resistance of the device to sudden exposures at extreme changes in temperature when soldering the lead wire.	MIL-STD-202: 210A MIL-STD-750: 2031 JIS C 7021: A-1
Solderability Test	1.T.Sol=230 ±5 2.Dwell time=5 ±1sec	This test intended to see soldering well performed or not.	MIL-STD-202: 208D MIL-STD-750: 2026 MIL-STD-883: 2003 JIS C 7021: A-2